





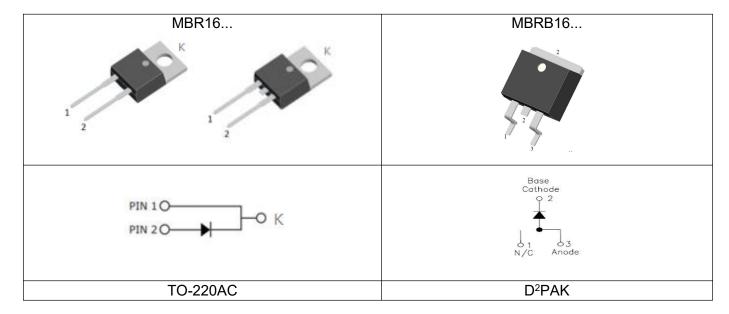
MBR1650/MBR1660/MBRB1650/MBRB1660 SCHOTTKY RECTIFIER

Features

- 150°C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- · High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection



Maximum Ratings@ 25°C unless otherwise specified

Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V _{RRM}	-	50	(MBR1650)	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
DC Blocking Voltage	$egin{array}{c} V_{RWM} \ V_{R} \end{array}$		60	(MBR1660)	V
Average Rectified Forward Current	I _{F (AV)}	Tc=132°C, In DC		16	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse		150	Α

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@16A, Pulse, T _J = 25 °C	0.59	0.75	V
	V _{F2}	@16A, Pulse, T _J = 125 ℃	0.56	0.65	V
Reverse Current *	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 \ ^{\circ}C$	0.03	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125 \degree C$	18	50	mA
Junction Capacitance	Ст	@ $V_R = 5V$, $T_C = 25$ °C $f_{SIG} = 1MHz$	593	1400	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nΗ
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

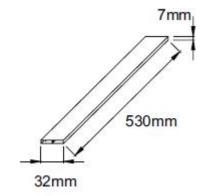
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	1.5	°C/W
Typical Thermal Resistance Case to Heat Sink	R _{θCS}	Mounting surface, smooth and greased	0.50	°C/W
Case Style	TO-220AC D ² PAK			

Tube Specification

Device	Package	Weight	Shipping
MBR16	TO-220AC	1.8g	50pcs / tube
MBRB16	D² PAK	1.85g	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AC)



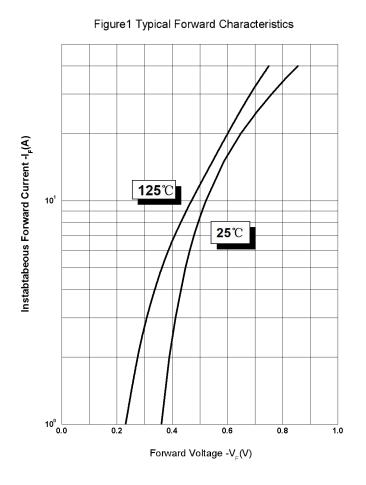
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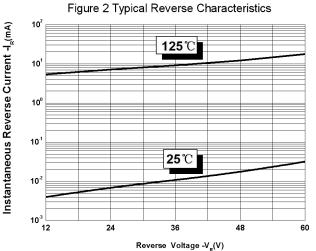






Ratings and Characteristics Curves





Junction Capacitance C_T (PF)

2

6

Reverse Voltage -V, (V)

10

Figure 3 Typical Junction Capacitance

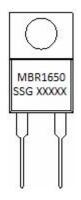








Marking Diagram





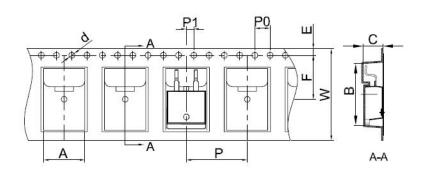
Where XXXXX is YYWWL

MBR = Device Type
B = Package type
16 = Forward Current (16A)
50/60 = Reverse Voltage (50/60V)
SSG = SSG
YY = Year

YY = Year WW = Week L = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification D²PAK



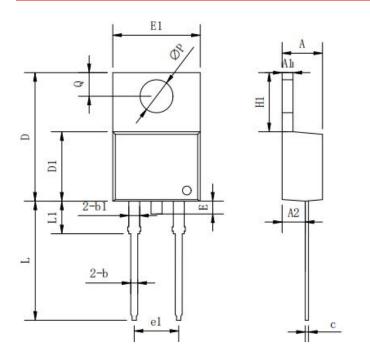
Symbol	Millimeters			
	Min.	Max.		
Α	10.70	10.90		
В	16.03	16.23		
С	5.11	5.31		
d	1.45	1.65		
E	1.65	1.85		
F	11.40	11.60		
P0	3.90	4.10		
Р	15.90	16.10		
P1	1.90	2.10		
W	23.90	24.30		





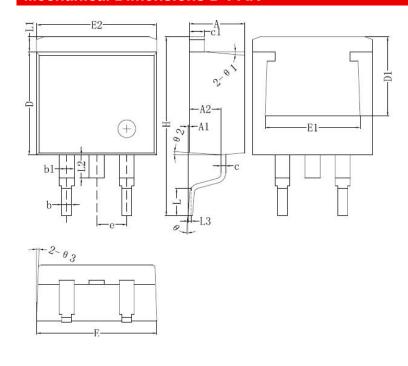


Mechanical Dimensions TO-220AC



Symbol	Dimensions in millimeters		
- ,	Min.	Typical	Max.
Α	3.56	-	4.83
A1	0.51	-	1.4
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
С	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	-	-	1.78
E1	9.65	10.16	10.67
e1	-	5.08	-
H1	5.84	-	6.86
L	12.7	-	14.73
L1	-	-	6.35
ФР	-	3.56	-
Q	2.54	-	3.43

Mechanical Dimensions D²PAK



Symbol	Dimensions in millimeters		
Syllibol	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
e	2.54BSC		
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	- 2.2		
L3	0.255BSC		
Θ	0 8°		

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MBR1650/MBRB1650 MBR1660/MBRB1660

Technical Data Data Sheet N0728, Rev. A





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